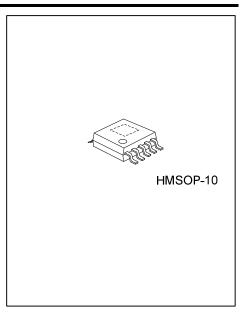
ALDR605 Advance CMOS IC

CAPLESS 2Vrms AUDIO LINE DRIVER WITH ADJUSTABLE GAIN

DESCRIPTION

The UTC **ALDR605** is a 2Vrms pop/click-free stereo line driver designed to allow the removal of the output DC-blocking capacitors for reduced component count and cost. The device is ideal for single supply electronics where size and cost are critical design parameters.

The UTC **ALDR605** is capable of driving 2Vrms into a $2.5 k\Omega$ load with 3.3 V supply voltage. The device has single input and uses external gain setting resistors that supports a gain range of $\pm 1 V/V$ to $\pm 10 V/V$. The **ALDR605** has build-in shutdown control for pop/click-free on/off control.

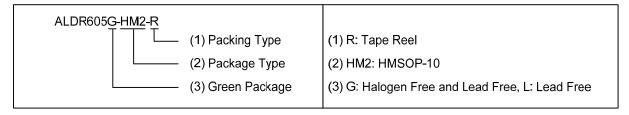


■ FEATURES

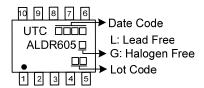
- * Integrated Charge pump generates negative supply rail
- * Provides flat frequency response from DC to 20kHz
- * Pop-Free under-voltage protection
- * Low noise and THD
- Typical THD+N = 0.001% (f =1kHz)
- * 2Vrms output voltage into 2.5kΩ load with 3.3V supply voltage
- * -40°C to +85°C operating temperature range

■ ORDERING INFORMATION

Ordering Number		Package	Packing	
Lead Free	Lead Free Halogen Free			
ALDR605L-HM2-R	ALDR605G-HM2-R	HMSOP-10	Tape Reel	

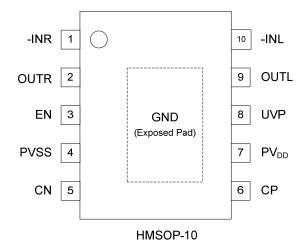


■ MARKING



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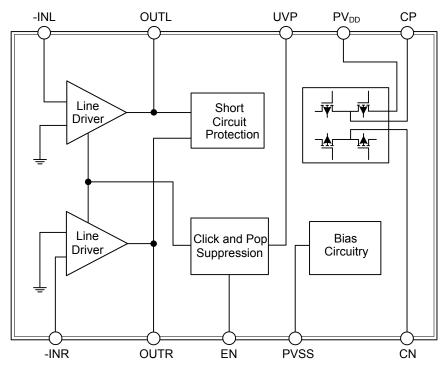
■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	-INR	Right Channel OPAMP Negative Input.
2	OUTR	Right Channel OPAMP Output.
3	EN	Enable Input. Active high.
4	PVSS	Negative Supply Voltage Output.
5	CN	Charge Pump Flying Capacitor Negative Terminal.
6	СР	Charge Pump Flying Capacitor Positive Terminal.
7	PV_{DD}	Positive Supply.
8	UVP	Under-Voltage Protection Input.
9	OUTL	Left Channel OPAMP Output.
10	-INL	Left Channel OPAMP Negative Input.
Exposed Pad	GND	Exposed Paddle. Can only be connected to GND.

■ BLOCK DIAGRAM



■ **ABSOLUTE MAXIMUM RATING** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage		-0.3 ~ 5.5	
Input Voltage		$V_{SS} - 0.3 \sim V_{DD} + 0.3$ V	
Minimum Load Impedance	R_L	600	Ω
EN to GND		$-0.3 \sim V_{DD} + 0.3$	V
Junction Temperature	T_J	+150	°C
Storage Temperature	T _{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

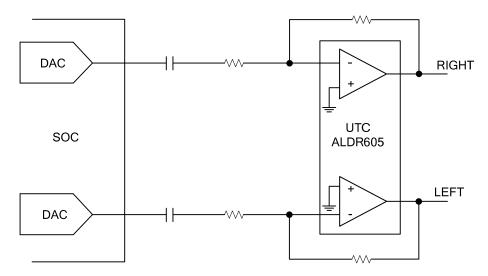
■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage		3 ~ 3.6	V
Operating Temperature		-40 ~ +85	°C

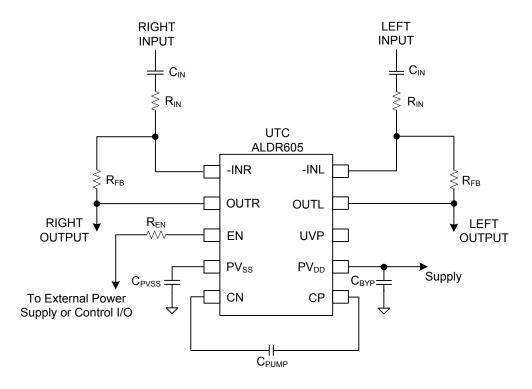
■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
ELECTRICAL CHARACTERIS		TEST CONDITIONS	IVIIIN	IIF	IVIAX	UNIT
DC Supply Voltage	V _{DD}		3		3.6	V
Output Offset Voltage	V _{DD} V _{OS}	V _{DD} =3.3V	3	1	5.5	mV
Power Supply Rejection Ratio	PSRR	V _{DD} =3.3V		97	3.3	dB
High-Level Output Voltage	V _{OH}	V_{DD} =3.3V, R_L =2.5k Ω	3.1	31		V
Low-Level Output Voltage	V _{OL}	V_{DD} =3.3V, R_{L} =2.5k Ω	0.1		-3.0	V
High-Level Input Current (EN)	II _{IH}	V _{DD} =3.3V, V _I =V _{DD}			1	μA
Low-Level Input Current (EN)		V _{DD} =3.3V, V _I =0V			1	μΑ
Supply Current	I _{DD}	V _{DD} =3.3V, Noload, EN=V _{DD}		10.8	14.5	mΑ
		Shutdownmode, V _{DD} =3V to 5V		0.13	0.25	mA
OPERATING CHARACTERISTICS (V_{DD} =3.3 V , R_L =2.5 $k\Omega$, C_{PUMP} = C_{PVSS} =1 μ F, C_{IN} =10 μ F, R_{IN} =10 $k\Omega$, R_{FB} =20 $k\Omega$.)						
Output Voltage (Outputs In Phase)	Vo	THD=1%, V _{DD} =3.3V, f=1kHz	2.05		15	Vrms
Total Harmonic Distortion Plus Noise	THD+N	V _O =2Vrms, f=1kHz		0.001		%
Crosstalk		V _O =2Vrms, f=1kHz		103		dB
Output Current Limit	Io	V _{DD} =3.3V		20		mA
Input Resistor Range	R _{IN}			10		kΩ
Feedback Resistor Range	R_{FB}			20		kΩ
Slew Rate				10		V/µs
Maximum Capacitive Load				220		pF
Noise Output Voltage	V_N	A-weighted, BW=20kHz		5.4		μVrms
Signal to Noise Ratio	SNR	A-weighted, V _O =2Vrms, BW=20kHz		108		dB
Unity Gain Bandwidth	G_{BW}			8		MHz
Open-Loop Voltage Gain	A _{VO}			100		dB
Charge Pump Frequency	F _{CP}		310	450	580	kHz
External Under-Voltage Detection	V_{UVP}		1.00	1.13	1.25	V
External Under-Voltage Detection Hysteresis Current	I _{Hys}			4.8		μА
EN PIN	Т		ı	1		
Input High Voltage	V_{INH}	EN	1.2			V
Input Low Voltage	V_{INL}	EN			0.3	V

TYPICAL OPERATION CIRCUIT



■ TYPICAL APPLICATION CIRCUIT



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